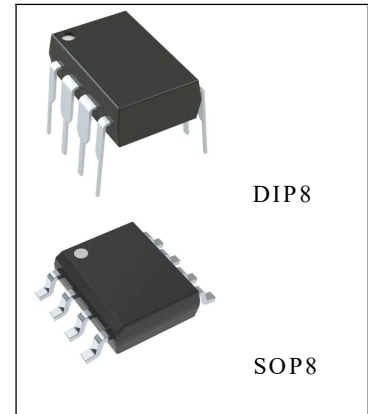


General Description

The D386 is a power amplifier designed for use in low voltage consumer applications. The gain is internally set to 20 to keep external part count low, but the addition of an external resistor and capacitor between pins 1 and 8 will increase the gain to any value from 20 to 200.

The inputs are ground referenced while the output automatically biases to one-half the supply voltage. The quiescent power drain is only 24 milliwatts when operating from a 6 volt supply, making the D386 ideal for battery operation.



Features

- Battery operation
- Minimum external parts
- Wide supply voltage range: 4V–12V
- Low quiescent current drain: 4mA
- Voltage gains from 20 to 200
- Available in 8 pin DIP package

Package Information

Part NO.	Package Description	Package Marking	Package Option
D386	DIP8	CHMC D386 SXXXX	50/Tube
D386(F)	SOP8	CHMC D386 SXXXX	100/Tube 4000/Reel

CHMC:Trademark

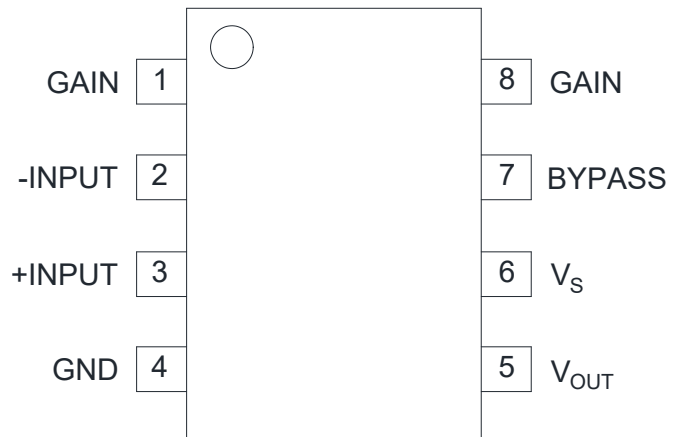
D386:Part NO.

SXXXX:Lot NO.

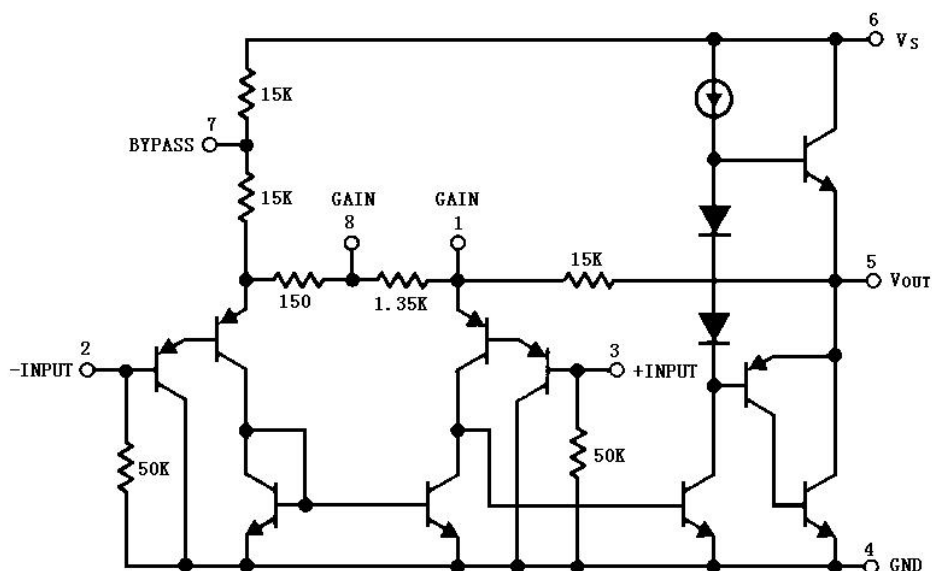
Applications

- AM-FM radio amplifiers
- Portable tape player amplifiers
- Intercoms
- TV sound systems
- Line drivers
- Ultrasonic drivers
- Small servo drivers
- Power converters

Pin Configuration



Equivalent Schematic And Connection Diagrams



Absolute Maximum Ratings (Ta=25°C)

Characteristic	Symbol	Value	Unit
Maximum Input Voltage	V _{IN}	± 0.4	V
Supply Voltage	V _{CC}	15	V
Maximum Power Dissipation	P _D	660	mW
Soldering temperature(10 sec.)	T _s	260	°C
Junction Temperature	T _j	150	°C
Operating Temperature	T _{amb}	-10~+70	°C
Storage Temperature	T _{stg}	-40~125	°C

Electrical Characteristics (Unless otherwise specified: $V_{CC}=6V$, $R_L=8\ \Omega$, $f=1kHz$, $T_{amb}=25^{\circ}C$)

Characteristics	Test conditions	Symbol	Min	Typ	Max	Unit
Operating Supply Voltage		V_{CC}			12	V
Quiescent Current	$V_{CC}=6V$, $V_{IN}=0$	I_{CC}	-	4	8	mA
Output Power	$V_{CC}=6V$, $R_L=8\Omega$, THD=10%	P_o	250	325		mW
	$V_{CC}=9V$, $R_L=8\Omega$, THD=10%		500	700		
Voltage Gain	$V_{CC}=6V$, $f=1kHz$	A_v	-	26	-	dB
	$10\ \mu F$ from Pin 1 to 8		-	46	-	
Bandwidth	$V_{CC}=6V$, Pins 1 and 8 open	BW	-	300	-	kHz
Total Harmonic Distortion	$V_{CC}=6V$, $R_L=8\ \Omega$, $P_o=125mW$, $f=1kHz$ Pins 1 and 8 open	THD	-	0.2	-	%
Power Supply Rejection Ratio	$V_{CC}=6V$, $f=1kHz$, $C_{BYPASS}=10\ \mu$ Pins 1 and 8 open referred to Output	PSRR		50		dB
Input Resistance		R_{IN}	-	50	-	k Ω
Input Bias Current	$V_{CC}=6V$, Pins 2 and 3 open	I_B	-	250	-	nA

Application Hints

Gain Control

To make the D386 a more versatile amplifier, two pins (1 and 8) are provided for gain control. With pins 1 and 8 open the $1.35k\Omega$ resistor sets the gain at 20 (26 dB). If a capacitor is put from pin 1 to 8, bypassing the $1.35k\Omega$ resistor, the gain will go up to 200 (46 dB). If a resistor is placed in series with the capacitor, the gain can be set to any value from 20 to 200. Gain control can also be done by capacitively coupling a resistor (or FET) from pin 1 to ground.

Additional external components can be placed in parallel with the internal feedback resistors to tailor the gain and frequency response for individual applications. For example, we can compensate poor speaker bass response by frequency shaping the feedback path. This is done with a series RC from pin 1 to 5 (paralleling the internal $15k\Omega$ resistor).

For 6 dB effective bass boost: $R \leq 15k\Omega$, the lowest value for good stable operation is $R = 10k\Omega$ if pin 8 is open. If pins 1 and 8 are bypassed then R as low as $2k\Omega$ can be used.

This restriction is because the amplifier is only compensated for closed-loop gains greater than 9.

Input Biasing

The schematic shows that both inputs are biased to ground with a $50\ k\Omega$ resistor. The

base current of the input transistors is about 250 nA, so the inputs are at about 12.5 mV when left open. If the dc source resistance driving the D386 is higher than 250 k Ω it will contribute very little additional offset (about 2.5 mV at the input, 50 mV at the output). If the dc source resistance is less than 10 kW, then shorting the unused input to ground will keep the offset low (about 2.5 mV at the input, 50 mV at the output). For dc source resistances between these values we can eliminate excess offset by putting a resistor from the unused input to ground, equal in value to the dc source resistance. Of course all offset problems are eliminated if the input is capacitively coupled.

When using the D386 with higher gains (bypassing the 1.35 k Ω resistor between pins 1 and 8) it is necessary to bypass the unused input, preventing degradation of gain and possible instabilities. This is done with a 0.1 μ F capacitor or a short to ground depending on the dc source resistance on the driven input.

Application Circuit

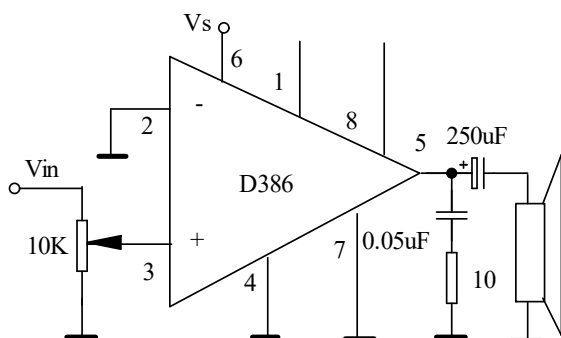


Fig1 Amplifier with Gain = 20
(Minimum Parts)

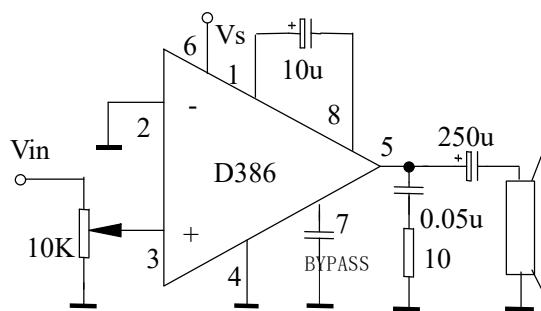


Fig2 Amplifier with Gain = 200

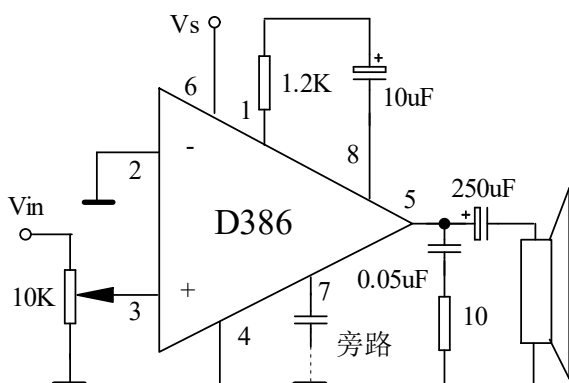


Fig3 Amplifier with Gain = 50

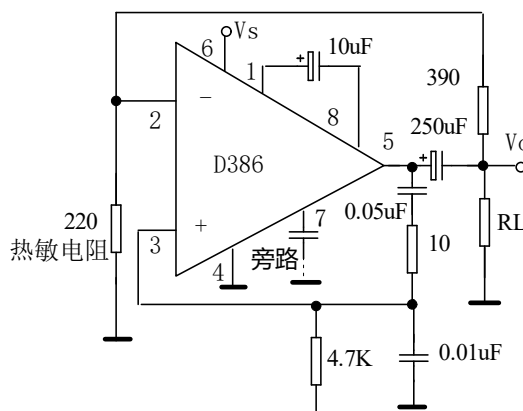


Fig4 Low Distortion Power
Wienbridge Oscillator

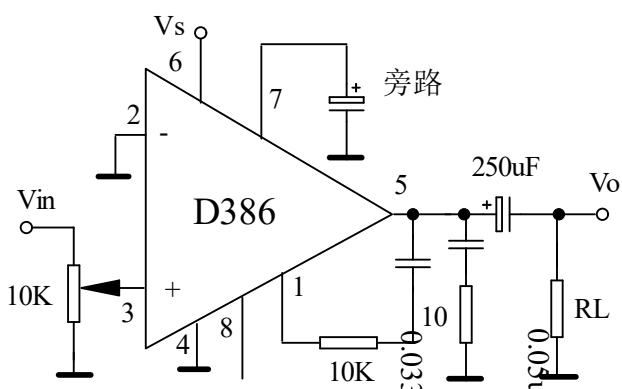


Fig5 Amplifier with Bass Boost

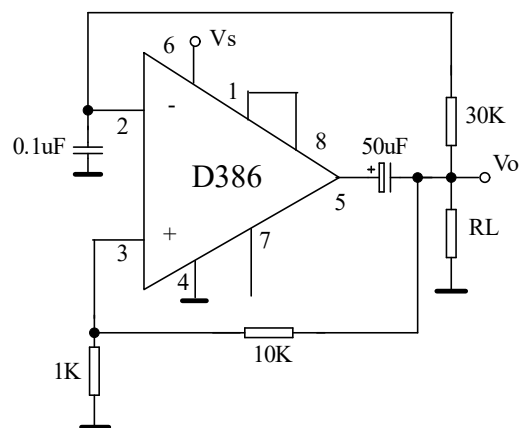


Fig6 Square Wave Oscillator

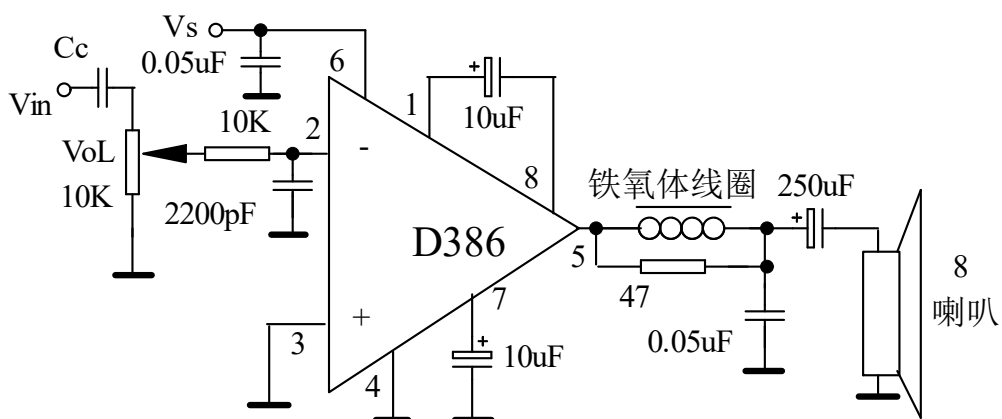
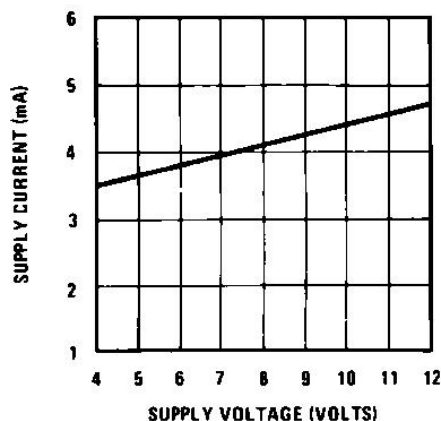


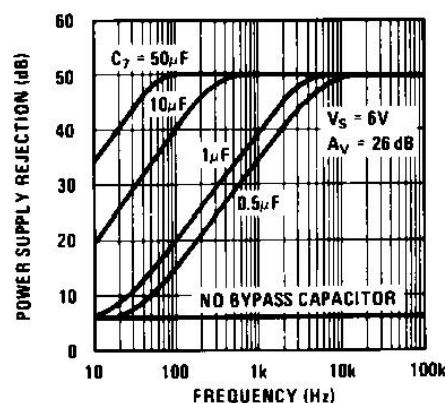
Fig7 AM Radio Power Amplifier

Typical Performance Characteristics

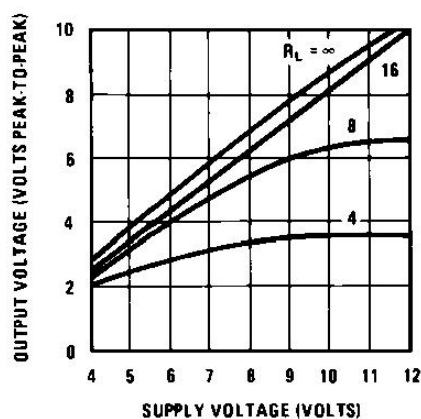
**Quiescent Supply Current
vs Supply Voltage**



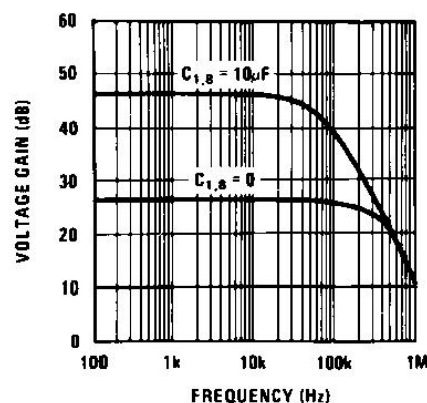
**Power Supply Rejection Ratio
(Referred to the Output)
vs Frequency**



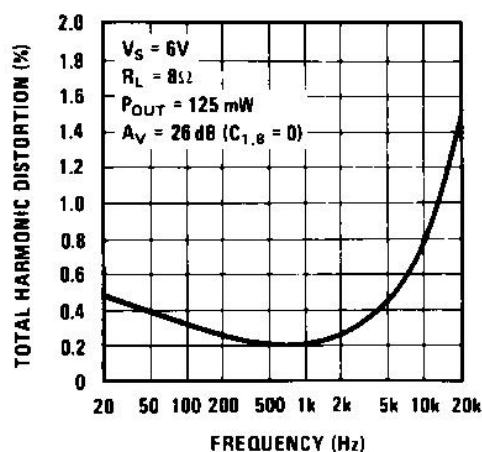
**Peak-to-Peak Output Voltage
Swing vs Supply Voltage**



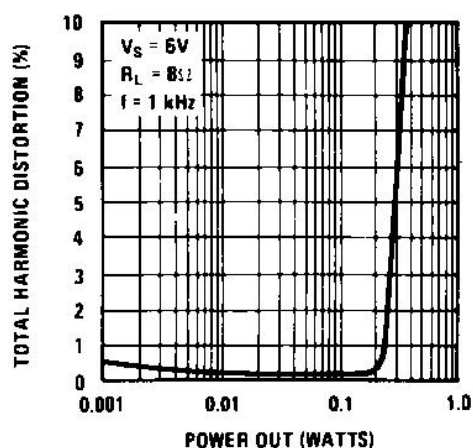
Voltage Gain vs Frequency



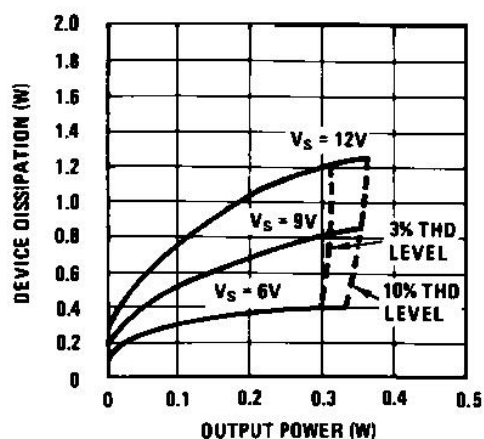
Distortion vs Frequency



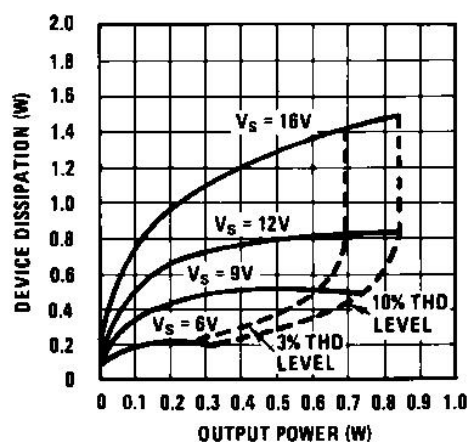
Distortion vs Output Power



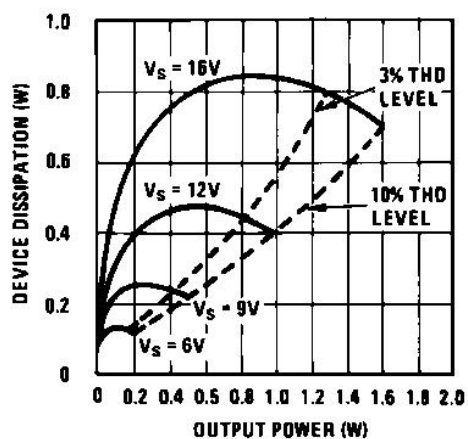
Device Dissipation vs Output Power—4 Ω Load



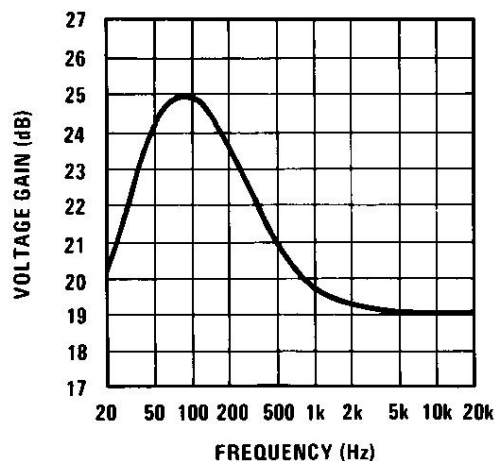
Device Dissipation vs Output Power—8 Ω Load



Device Dissipation vs Output Power—16 Ω Load



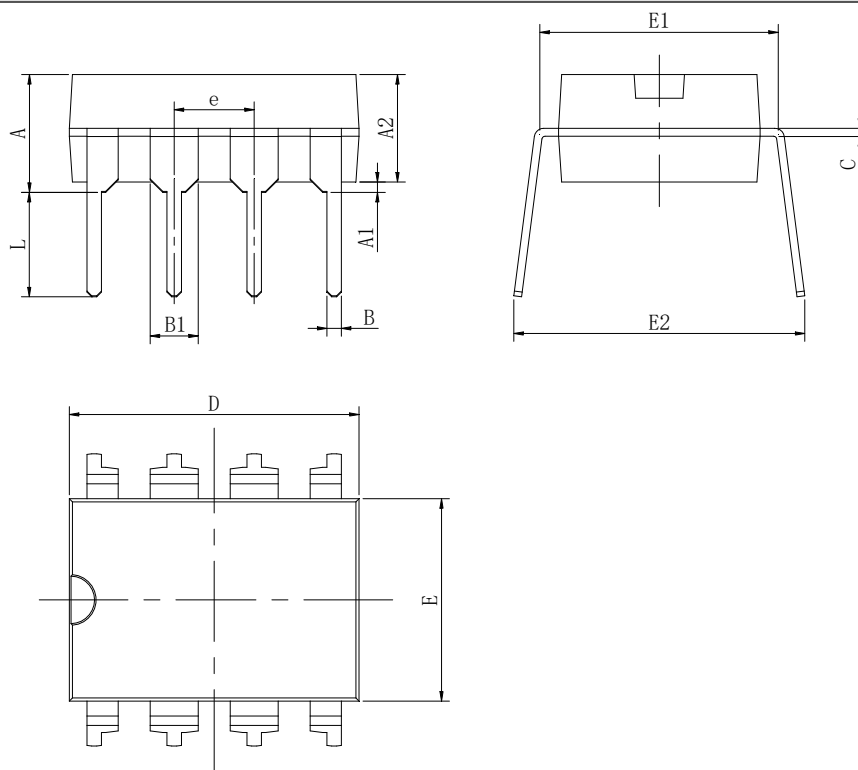
Frequency Response with Bass Boost



Outline Dimensions

DIP8

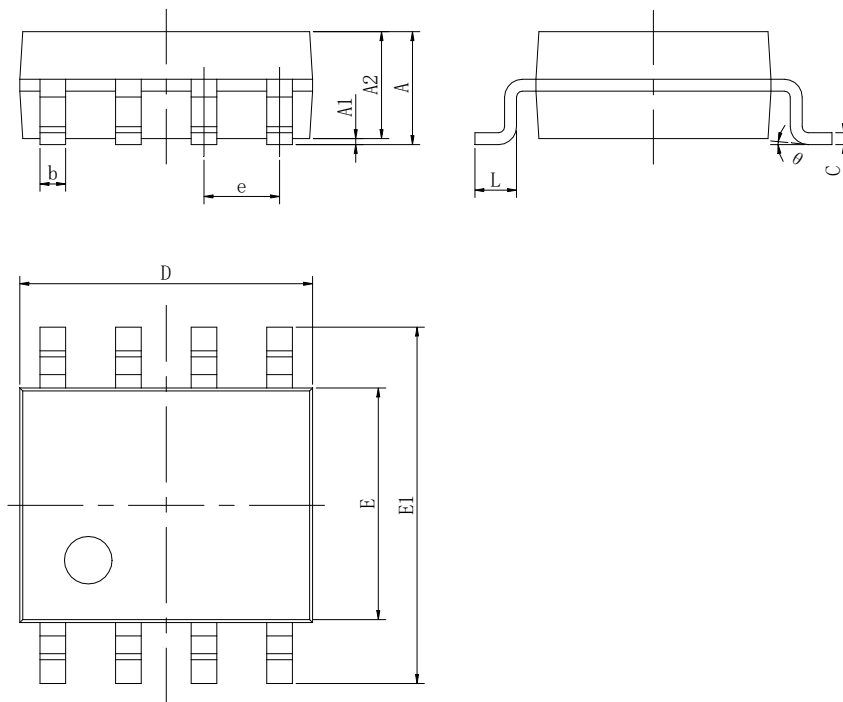
Unit: mm



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.710	4.310	0.146	0.170
A1	0.510		0.020	
A2	3.200	3.600	0.126	0.142
B	0.380	0.570	0.015	0.022
B1	1.524(BSC)		0.060(BSC)	
C	0.204	0.360	0.008	0.014
D	9.000	9.400	0.354	0.370
E	6.200	6.600	0.244	0.260
E1	7.320	7.920	0.288	0.312
e	2.540(BSC)		0.100(BSC)	
L	3.000	3.600	0.118	0.142
E2	8.400	9.000	0.331	0.354

SOP8

Unit: mm



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.800	0.053	0.071
A1	0.000	0.250	0.000	0.010
A2	1.250	1.550	0.053	0.061
b	0.300	0.510	0.011	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.201
E	3.800	4.000	0.150	0.157
E1	5.800	6.300	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

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